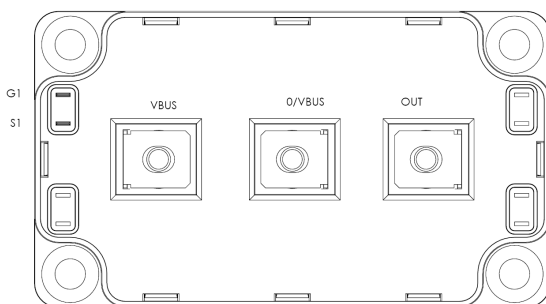
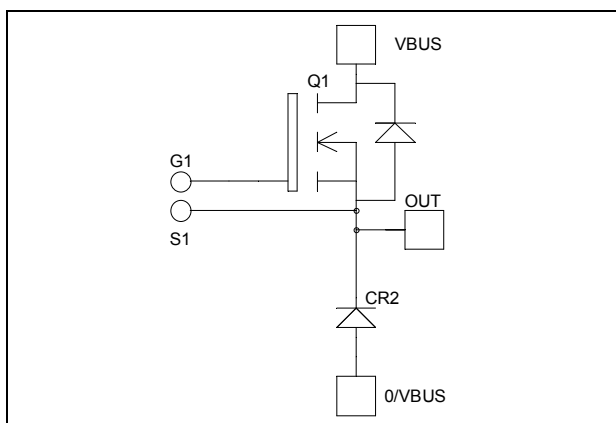


## Buck chopper MOSFET Power Module

$V_{DSS} = 500V$

$R_{DSon} = 17m\Omega$  typ @  $T_j = 25^\circ C$

$I_D = 180A$  @  $T_c = 25^\circ C$



### Application

- AC and DC motor control
- Switched Mode Power Supplies

### Features

- Power MOS 7<sup>®</sup> MOSFETs
  - Low  $R_{DSon}$
  - Low input and Miller capacitance
  - Low gate charge
  - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

### Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

### Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
$V_{DSS}$	Drain - Source Breakdown Voltage	500	V
$I_D$	Continuous Drain Current	$T_c = 25^\circ C$ 180 $T_c = 80^\circ C$ 135	A
$I_{DM}$	Pulsed Drain current	720	
$V_{GS}$	Gate - Source Voltage	$\pm 30$	V
$R_{DSon}$	Drain - Source ON Resistance	20	$m\Omega$
$P_D$	Maximum Power Dissipation	$T_c = 25^\circ C$ 1250	W
$I_{AR}$	Avalanche current (repetitive and non repetitive)	51	A
$E_{AR}$	Repetitive Avalanche Energy	50	mJ
$E_{AS}$	Single Pulse Avalanche Energy	3000	



CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on [www.microsemi.com](http://www.microsemi.com)

**All ratings @  $T_j = 25^\circ\text{C}$  unless otherwise specified**

**Electrical Characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 500V$ $T_j = 25^\circ\text{C}$			400	$\mu\text{A}$
		$V_{GS} = 0V, V_{DS} = 400V$ $T_j = 125^\circ\text{C}$			2000	
$R_{DS(on)}$	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 90A$		17	20	$\text{m}\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 10\text{mA}$	3		5	V
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 30V, V_{DS} = 0V$			$\pm 200$	nA

**Dynamic Characteristics**

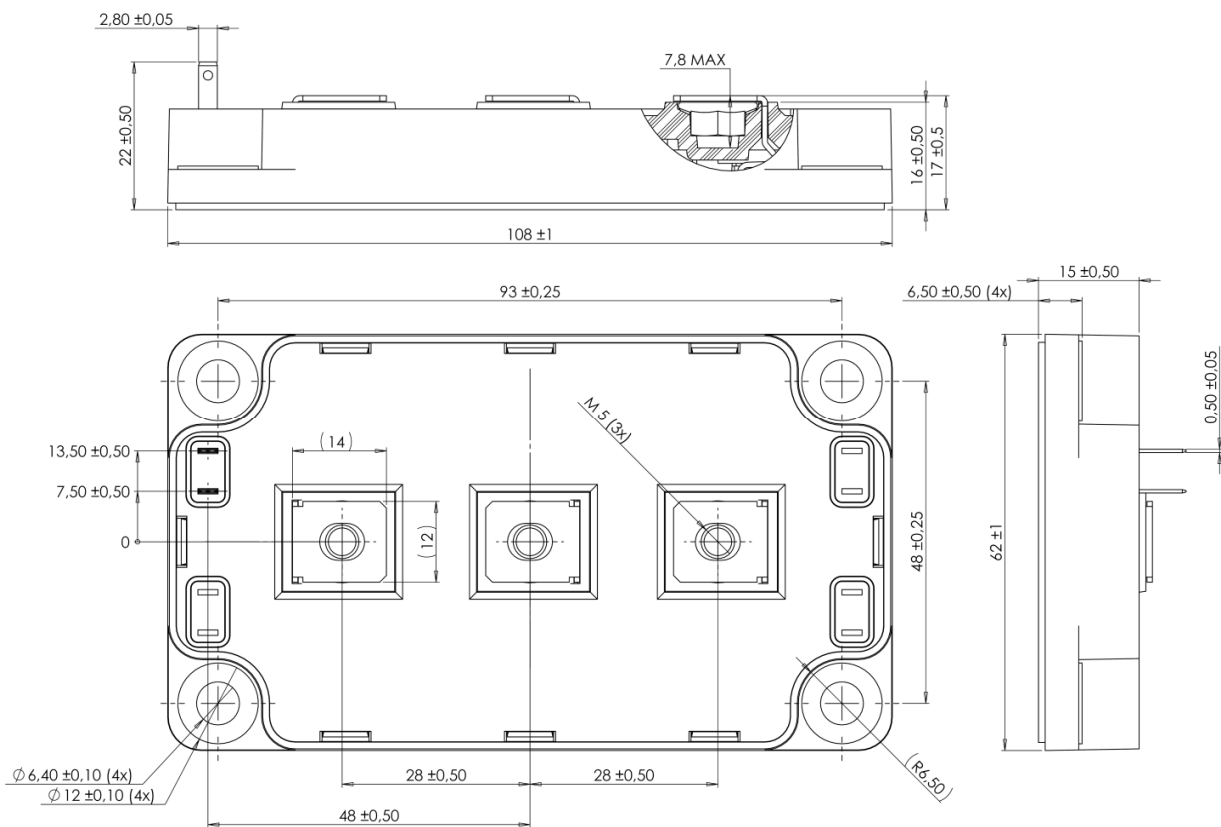
Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$		28		nF
$C_{oss}$	Output Capacitance	$V_{DS} = 25V$		5.6		
$C_{rss}$	Reverse Transfer Capacitance	$f = 1\text{MHz}$		0.36		
$Q_g$	Total gate Charge	$V_{GS} = 10V$ $V_{Bus} = 250V$ $I_D = 180A$		560		nC
$Q_{gs}$	Gate – Source Charge			160		
$Q_{gd}$	Gate – Drain Charge			280		
$T_{d(on)}$	Turn-on Delay Time	<b>Inductive switching @ <math>125^\circ\text{C}</math></b> $V_{GS} = 15V$ $V_{Bus} = 333V$ $I_D = 180A$ $R_G = 0.5\Omega$		21		ns
$T_r$	Rise Time			38		
$T_{d(off)}$	Turn-off Delay Time			75		
$T_f$	Fall Time			93		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ <math>25^\circ\text{C}</math></b> $V_{GS} = 15V, V_{Bus} = 333V$ $I_D = 180A, R_G = 0.5\Omega$		4140		$\mu\text{J}$
$E_{off}$	Turn-off Switching Energy			3380		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ <math>125^\circ\text{C}</math></b> $V_{GS} = 15V, V_{Bus} = 333V$ $I_D = 180A, R_G = 0.5\Omega$		6224		$\mu\text{J}$
$E_{off}$	Turn-off Switching Energy			4052		

**Chopper diode ratings and characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage		600			V
$I_{RM}$	Maximum Reverse Leakage Current	$V_R = 600V$	$T_j = 25^\circ\text{C}$		500	$\mu\text{A}$
			$T_j = 125^\circ\text{C}$		1000	
$I_F$	DC Forward Current	$T_c = 70^\circ\text{C}$		180		A
$V_F$	Diode Forward Voltage	$I_F = 180A$		1.6	1.8	V
		$I_F = 360A$		1.9		
		$I_F = 180A$ $T_j = 125^\circ\text{C}$		1.4		
$t_{rr}$	Reverse Recovery Time	$I_F = 180A$ $V_R = 400V$ $di/dt = 600A/\mu\text{s}$	$T_j = 25^\circ\text{C}$	130		ns
			$T_j = 125^\circ\text{C}$	170		
$Q_{rr}$	Reverse Recovery Charge	$T_j = 25^\circ\text{C}$		660		nC
			$T_j = 125^\circ\text{C}$	2760		

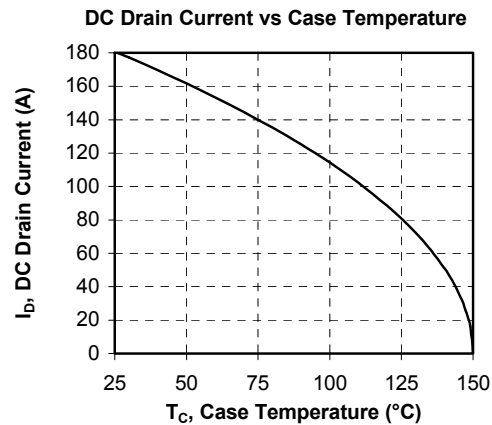
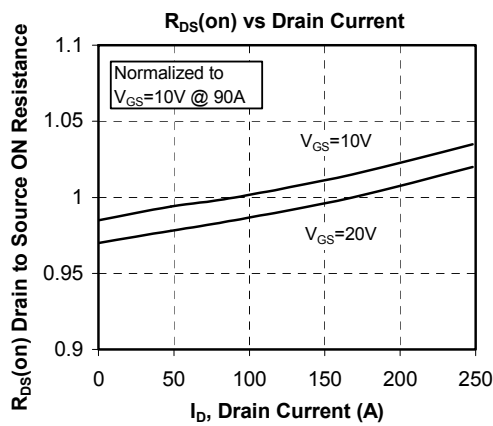
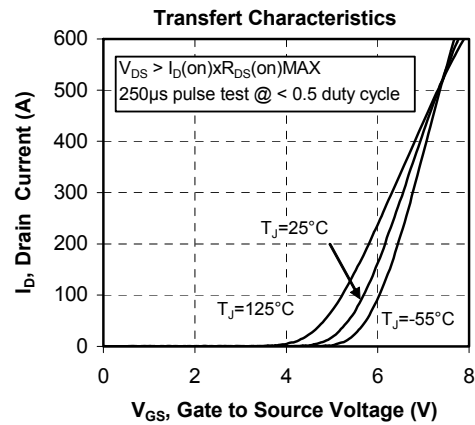
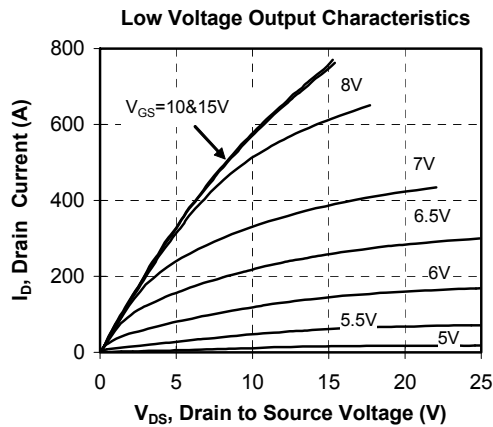
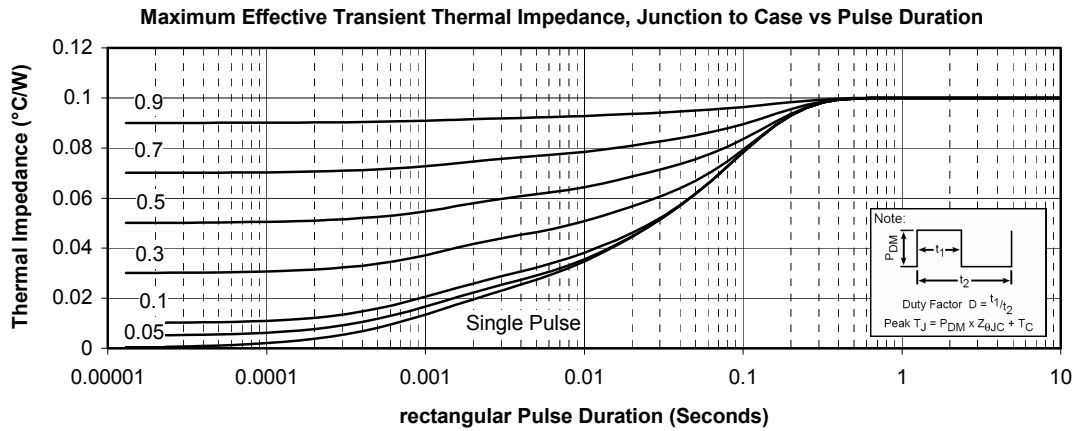
**Thermal and package characteristics**
*Symbol Characteristic*

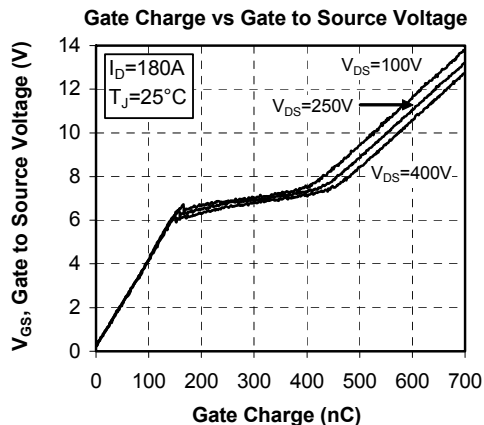
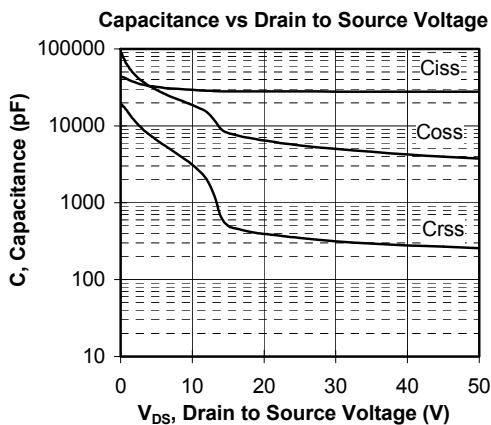
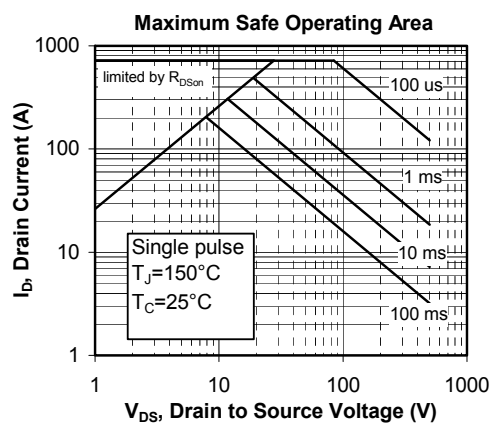
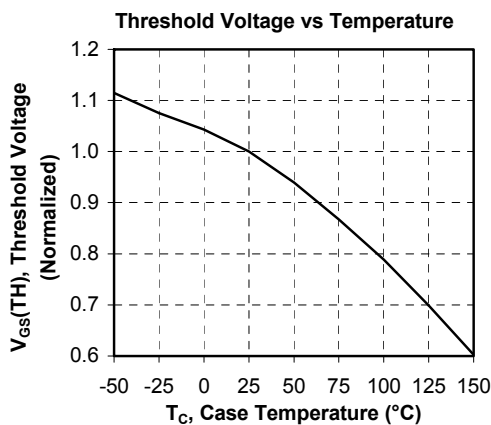
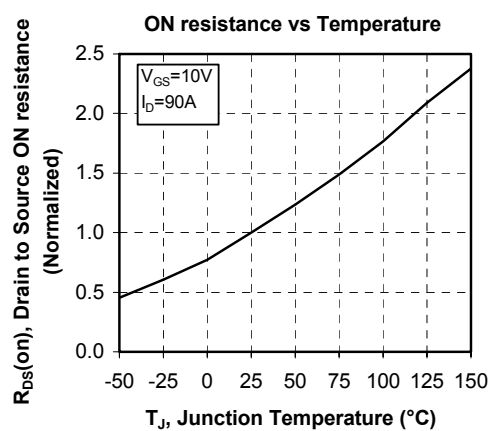
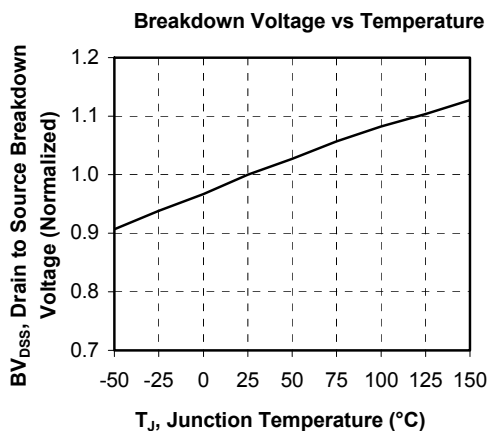
			<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>
$R_{thJC}$	Junction to Case Thermal Resistance	Transistor			0.1	°C/W
		Diode			0.32	
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case $t = 1$ min, 50/60Hz		4000			V
$T_J$	Operating junction temperature range		-40		150	°C
$T_{STG}$	Storage Temperature Range		-40		125	
$T_C$	Operating Case Temperature		-40		100	
Torque	Mounting torque	To heatsink	M6	3	5	N.m
		For terminals	M5	2	3.5	
Wt	Package Weight				300	g

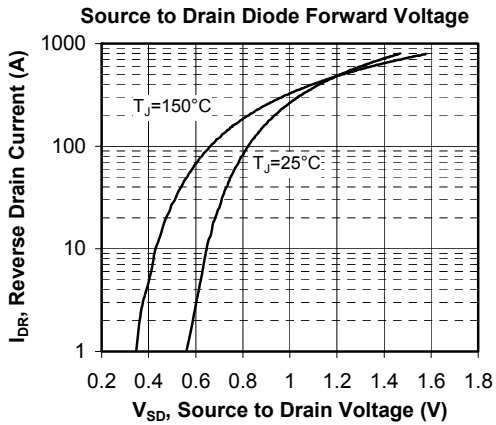
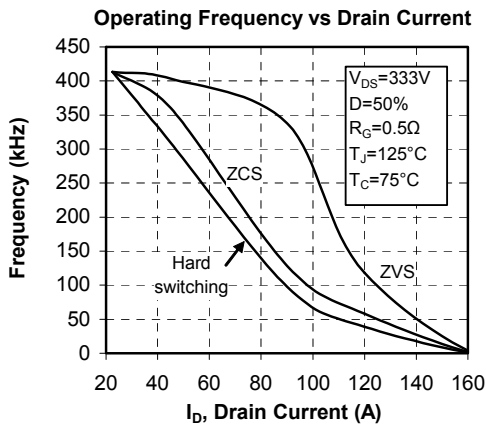
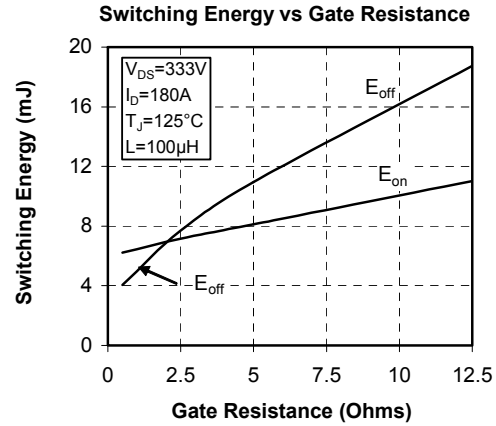
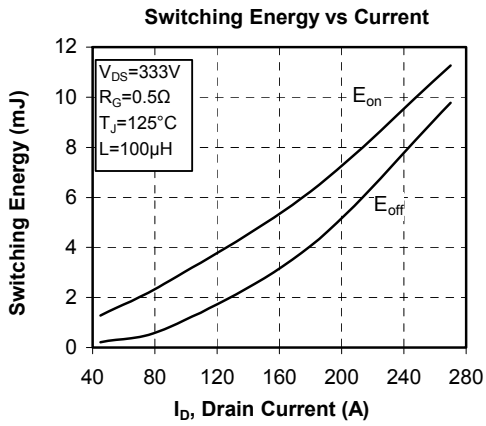
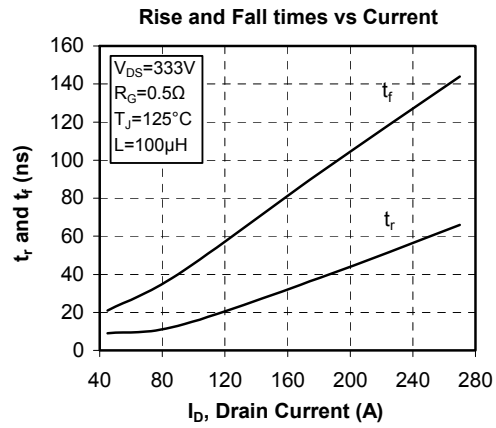
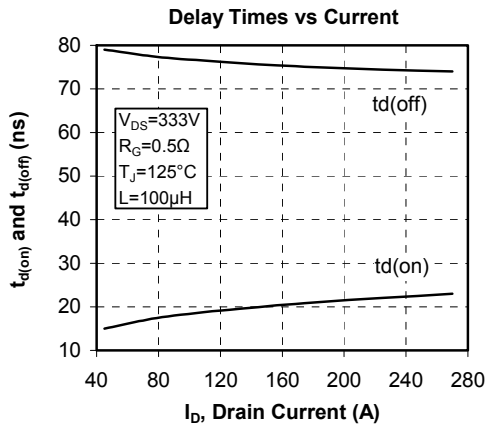
**SP6 Package outline (dimensions in mm)**


See application note APT0601 - Mounting Instructions for SP6 Power Modules on [www.microsemi.com](http://www.microsemi.com)

## Typical Performance Curve







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